



P-Channel 30-V (D-S) MOSFET

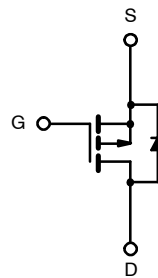
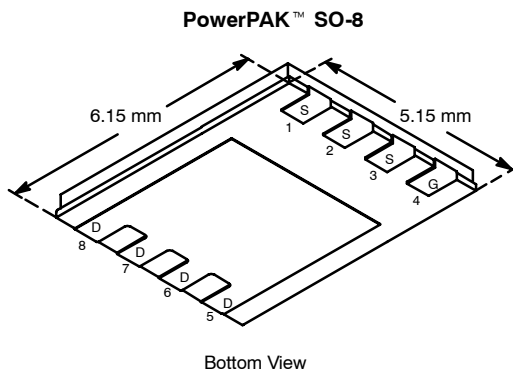
PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-30	0.005 @ $V_{GS} = -10$ V	-24
	0.0095 @ $V_{GS} = -4.5$ V	-17

FEATURES

- TrenchFET® Power MOSFETS
- New Low Thermal Resistance PowerPAK™ Package with Low 1.07-mm Profile

APPLICATIONS

- Battery and Load Switching
 - Notebook Computers
 - Notebook Battery Packs



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)					
Parameter	Symbol	10 secs	Steady State	Unit	
Drain-Source Voltage	V_{DS}	-30		V	
Gate-Source Voltage	V_{GS}	± 20			
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	I_D	$T_A = 25^\circ\text{C}$	-24	-14	A
		$T_A = 70^\circ\text{C}$	-19	-11	
Pulsed Drain Current	I_{DM}	-60			
continuous Source Current (Diode Conduction) ^a	I_S	-4.5	-1.6		
Maximum Power Dissipation ^a	P_D	$T_A = 25^\circ\text{C}$	5.4	1.9	W
		$T_A = 70^\circ\text{C}$	3.4	1.2	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150		$^\circ\text{C}$	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 10$ sec	18	23	$^\circ\text{C/W}$
		Steady State	50	65	
Maximum Junction-to-Case (Drain)	R_{thJC}	1.0	1.5		

Notes

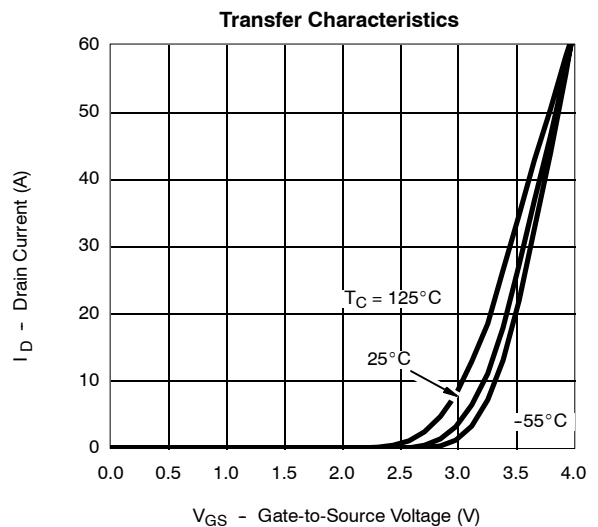
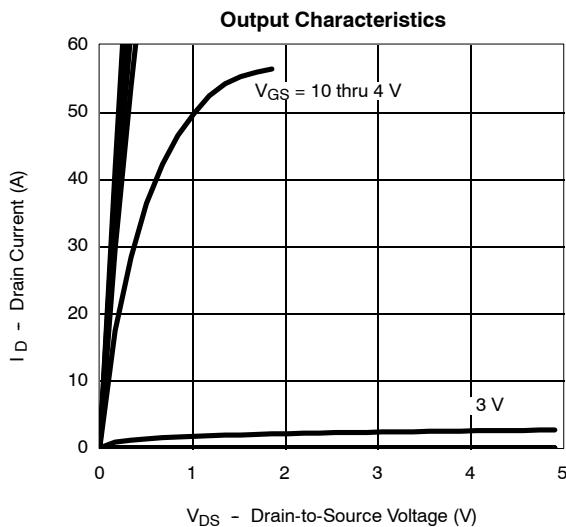
a. Surface Mounted on 1" x 1" FR4 Board.

SPECIFICATIONS (T _J = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.0		-3.0	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -24 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -24 V, V _{GS} = 0 V, T _J = 70 °C			-10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = -5 V, V _{GS} = -10 V	-30			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = -10 V, I _D = -24 A		0.0041	0.005	Ω
		V _{GS} = -4.5 V, I _D = -17 A		0.0077	0.0095	
Forward Transconductance ^a	g _{fs}	V _{DS} = -15 V, I _D = -24 A		70		S
Diode Forward Voltage ^a	V _{SD}	I _S = -2.9 A, V _{GS} = 0 V		-0.75	-1.1	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = -15 V, V _{GS} = -10 V, I _D = -24 A		120	180	nC
Gate-Source Charge	Q _{gs}			18.3		
Gate-Drain Charge	Q _{gd}			33.2		
Turn-On Delay Time	t _{d(on)}	V _{DD} = -15 V, R _L = 15 Ω I _D ≅ -1 A, V _{GEN} = -10 V, R _G = 6 Ω		25	40	ns
Rise Time	t _r			40	65	
Turn-Off Delay Time	t _{d(off)}			220	350	
Fall Time	t _f			125	200	
Gate Resistance	R _g				4	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = -2.9 A, di/dt = 100 A/μs		87	135	ns

Notes

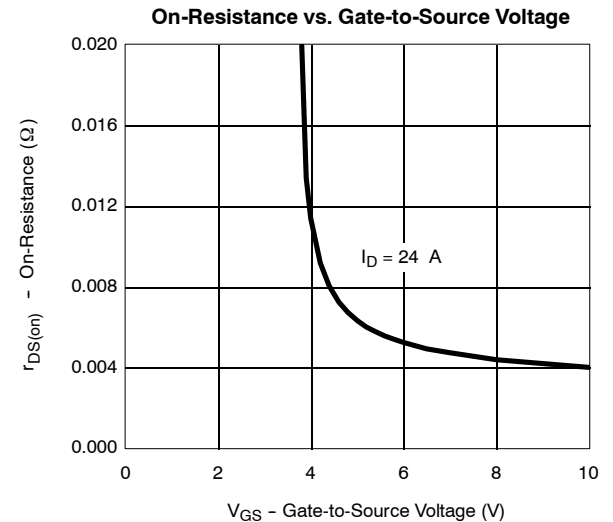
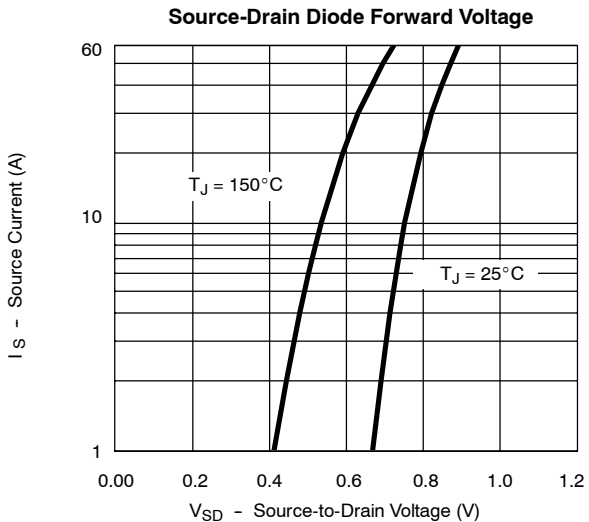
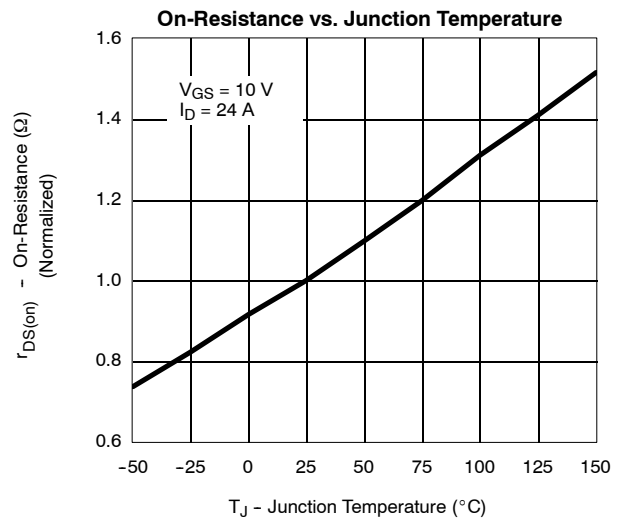
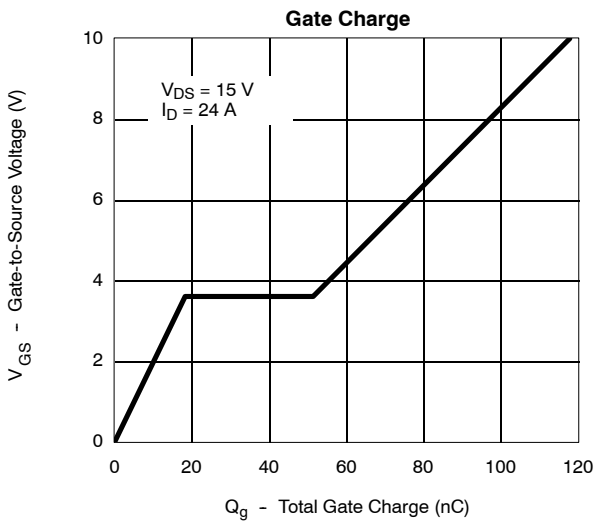
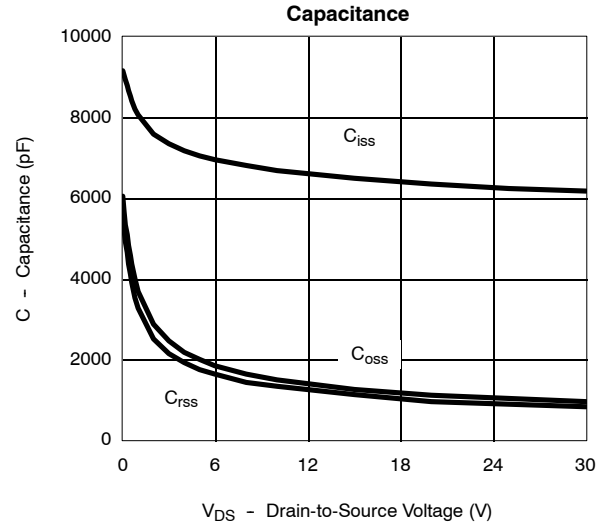
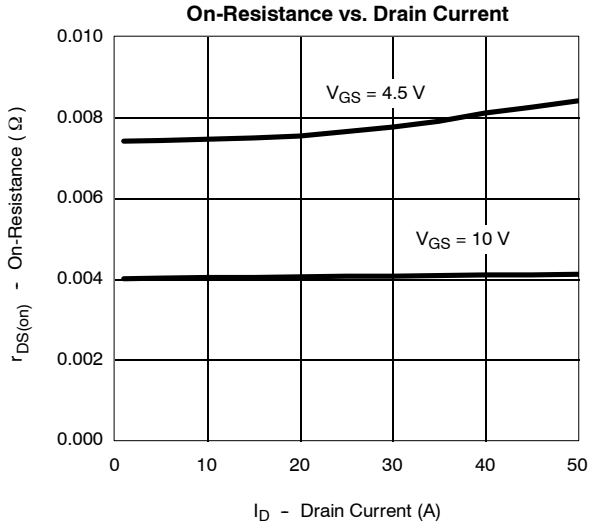
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)

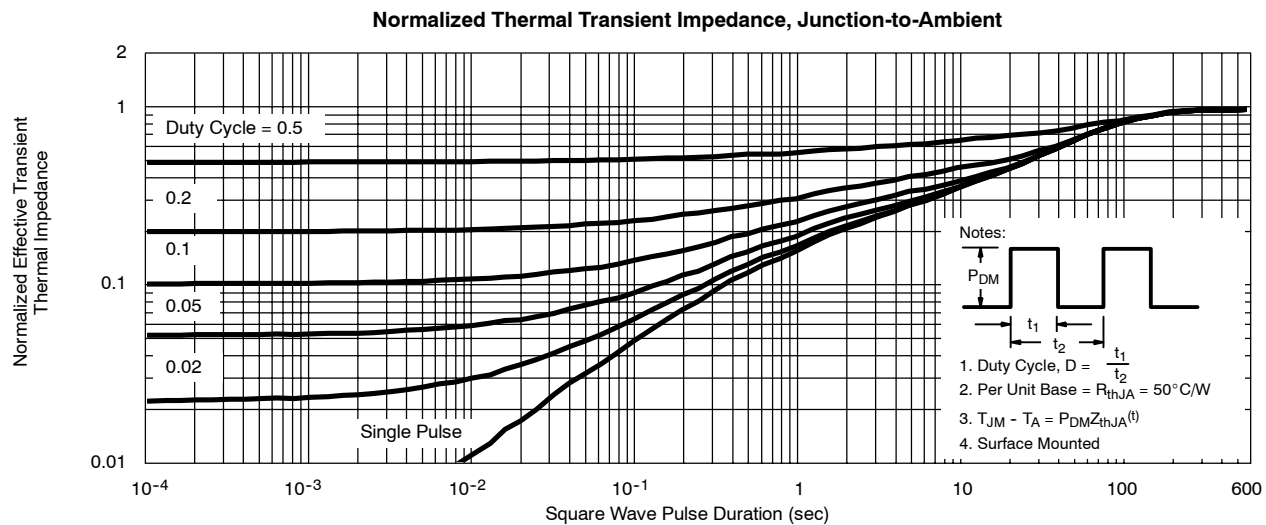
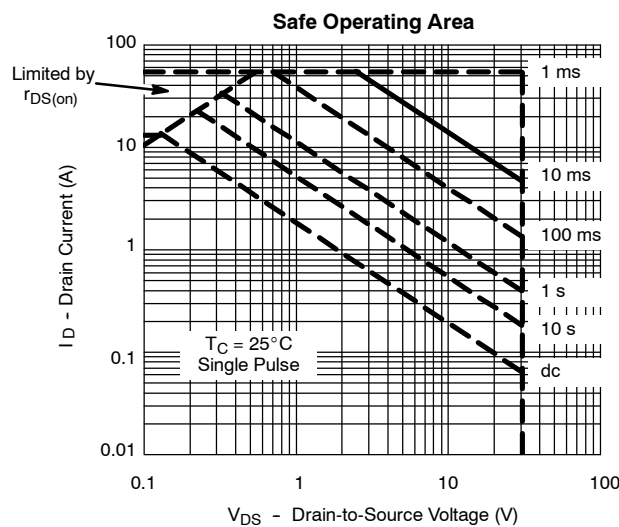
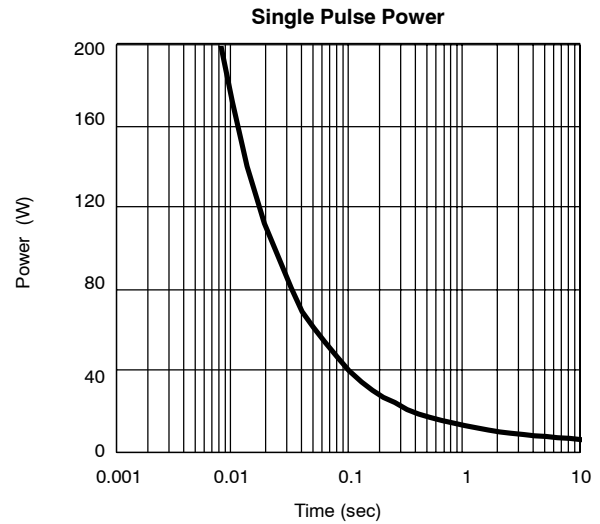
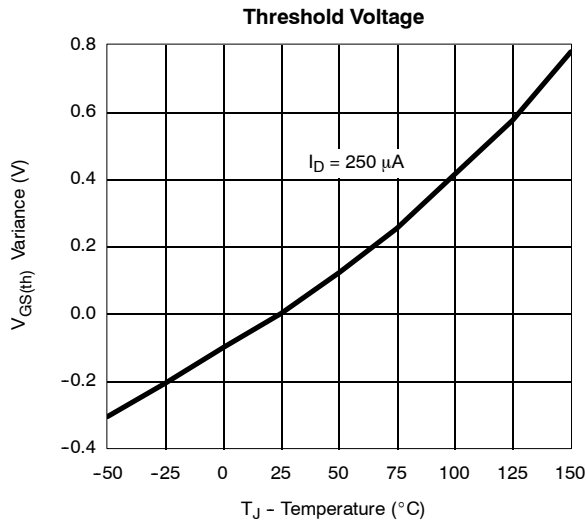




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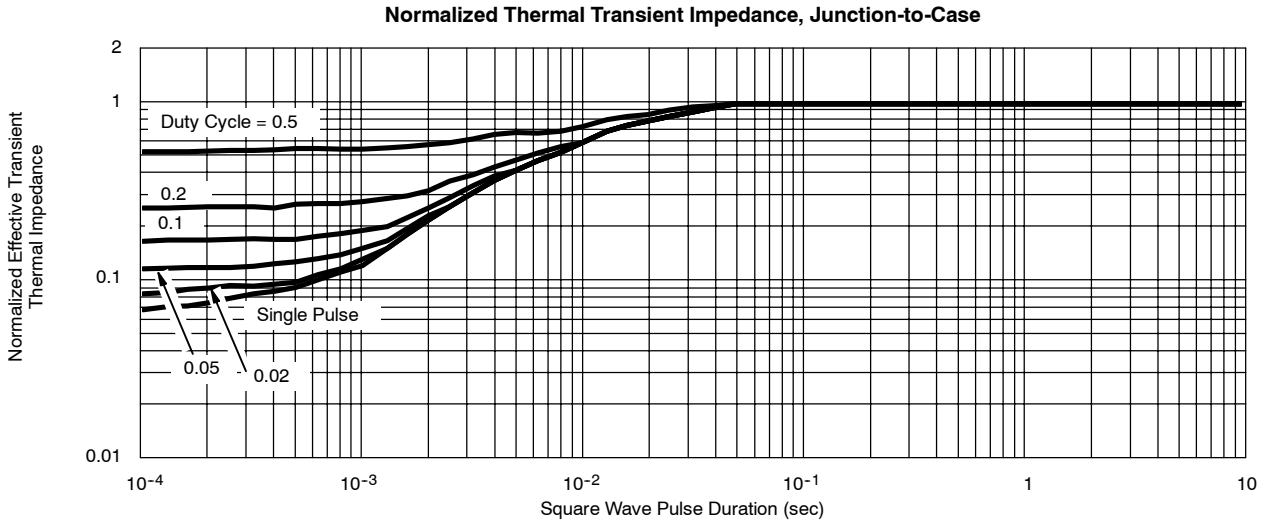


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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





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